

MAPCGM0003-DIE

RO-P-DS-3045 A **Preliminary Information**

Features

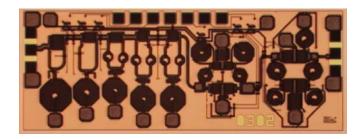
- ♦ 6 Bit Phase Shifter (0° ~ 354°, CW)
- ◆ TTL Control Inputs
- ♦ MSAG™ Process

Description

The MAPCGM0003-Die is a 6-bit Phase Shifter with Parallel Input Control. This product is fully matched to 50 ohms on both the input and output. It can be used to obtain a phase shift of 5.6° to 354° Clockwise.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate MESFET Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG™ process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



Primary Applications

- Satellite Communication
- Phased Array Radar

Electrical Characteristics: $T_B = 40^{\circ}C^1$, $Z_0 = 50\Omega$, $V_{EE} = -5V$

Parameter	Symbol	Typical	Units
Bandwidth	f	2.3-4.1	GHz
Insertion Loss	IL 5.7		dB
Input VSWR (At Reference)	VSWR	1.5:1	
Output VSWR (At Reference)	VSWR	1.2:1	
RMS Phase Error	RMS	6	0
Phase Range	ΔΦ	354	0
Gain Variation over all Phase Shifter settings	ΔG	< 3	dB
Source Current	I _{EE}	< 10	mA
Input Third Order Intercept	ITOI	36	dBm
Input 1-dB Compression Point	P_{1dB}	23	dBm

1. T_B = MMIC Base Temperature

- M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes
- no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

information.





MAPCGM0003-DIE RO-P-DS-3045 A **Preliminary Information**

Maximum Operating Conditions ¹

Parameter	Symbol	Absolute Maximum	Units
Input Power	P _{IN}	30	dBm
Source Supply Voltage	V_{EE}	-4.8	V
Source Current (No RF)	l _{EEQ}	20	mA
Junction Temperature	Tj	180	°C
Storage Temperature	T _{STG}	-55 to +150	°C

^{1.} Operation outside of these ranges may reduce product reliability. Operation at other than the typical values may result in performance outside the guaranteed limits.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур	Max	Unit
Source Voltage	V_{EE}	-5.2	-5	-4.8	V
Control Voltage	V control pads				
Logic High		3	5	5	V
Logic Low		0	0	0.4	V

Operating Instructions

This device is static and light sensitive. The digital circuitry operation can be impaired under high intensity light, e.g. microscope light. Please handle with care. To operate the device, follow these steps.

- 1. Power Up: Apply $V_{EE} = -5 \text{ V}$.
- 2. Apply Logic Voltages to control Circuits as listed in Recommended Operating Conditions
- 3. Power Down: Set $V_{EE} = 0$



- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298







MAPCGM0003-DIE RO-P-DS-3045 A Preliminary Information

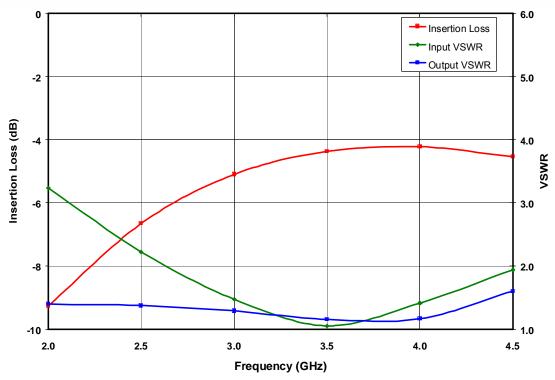


Figure 1. Reference State Insertion Loss, Input and Output VSWR vs. Frequency

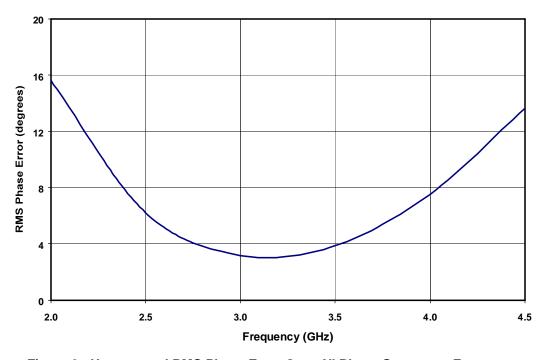


Figure 2. Uncorrected RMS Phase Error Over All Phase States vs. Frequency

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAPCGM0003-DIE

RO-P-DS-3045 A Preliminary Information

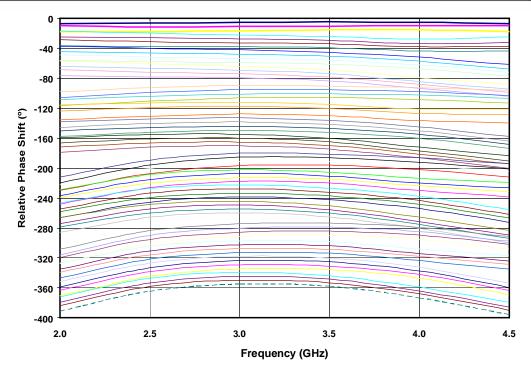


Figure 3. Relative Phase Shift vs. Frequency For All Phase States

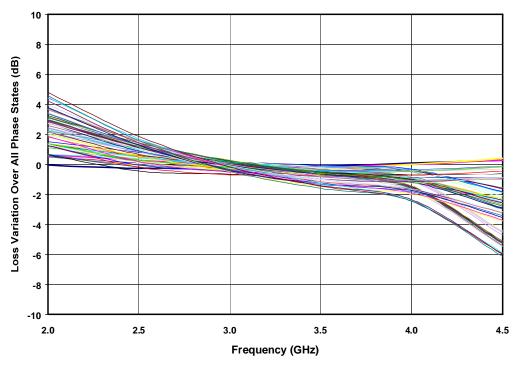


Figure 4. Loss Variation Over All Phase States vs. Frequency

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAPCGM0003-DIE RO-P-DS-3045 A **Preliminary Information**

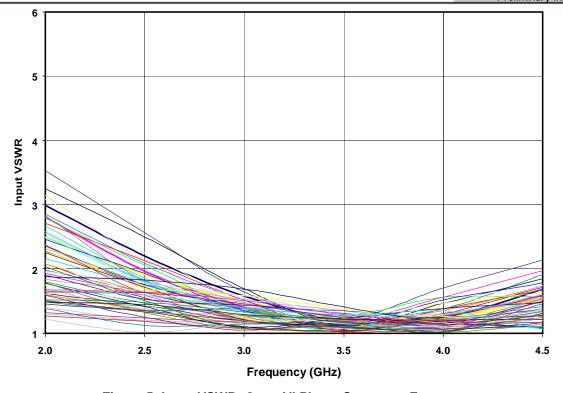


Figure 5. Input VSWR Over All Phase States vs. Frequency

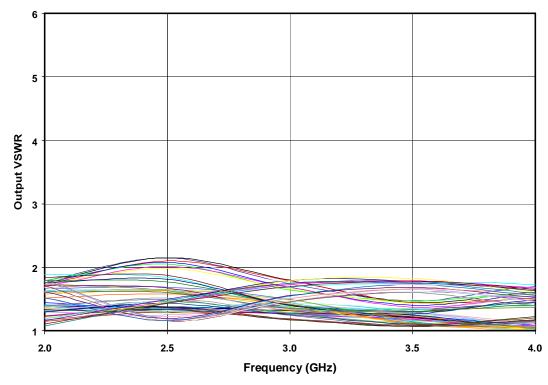


Figure 6. Output VSWR Over All Phase States vs. Frequency

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAPCGM0003-DIE RO-P-DS-3045 A **Preliminary Information**

Mechanical Information

Chip Size: 3.814 x 1.355 x 0.075 mm (150 x 55 x 3 mils)

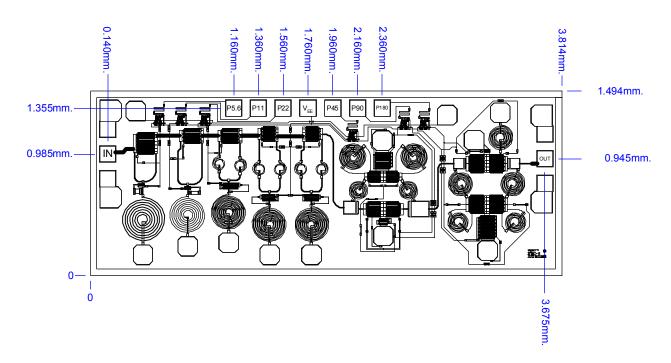


Figure 5. Die Layout

Bond Pad Dimensions

Pad	Size (μm)	Size (mils)
RF In and Out	100 x 200	4 x 8
DC Supply Voltage VEE	125 x 125	5 x 5
DC Control Voltage VC	125 x 125	5 x 5

- North America Tel: 800.366.2266 / Fax: 978.366.2266
- **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAPCGM0003-DIE RO-P-DS-3045 A Preliminary Information

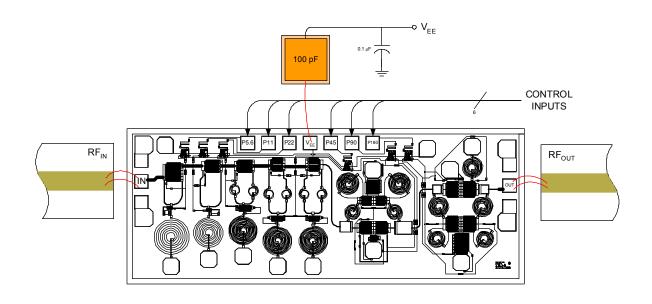


Figure 6. Recommended bonding diagram for pedestal mount. Support circuitry typical of MMIC characterization.

Assembly Instructions:

Die attach: Use AuSn (80/20) 1-2 mil. preform solder. Limit time @ 300 °C to less than 5 minutes.

Wirebonding: Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC pad connections, use either ball or wedge bonds. For best RF performance, use wedge bonds of shortest length, although ball bonds are also acceptable.

Biasing Note: Must apply negative bias to V_{EE} before applying positive bias to Control Pads.

North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] **Europe** Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298